

RELAY DRIVERS, LAMP DRIVERS,
MOTOR DRIVERS AND STROBES APPLICATION.

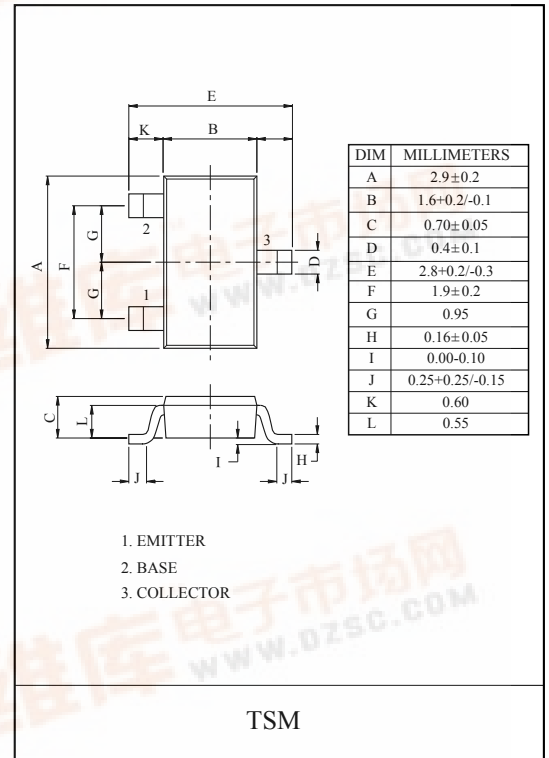
FEATURES

- Adoption of MBIT Processes.
- Large Current Capacitance.
- Low Collector-to-Emitter Saturation Voltage.
- High Speed Switching.
- Ultrasmall Package facilitates miniaturization in end products.
- High Allowable Power Dissipation.
- Complementary to KTA1544T.

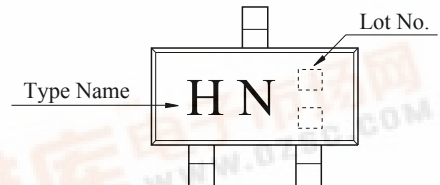
MAXIMUM RATING (Ta=25°C)

CHARACTERISTIC		SYMBOL	RATING	UNIT
Collector-Base Voltage		V _{CB0}	30	V
Collector-Emitter Voltage		V _{CEO}	30	V
Emitter-Base Voltage		V _{EBO}	6	V
Collector Current	DC	I _C	2	A
	Pulse	I _{CP}	4	
Base Current		I _B	400	mA
Collector Power Dissipation		P _C *	0.9	W
Junction Temperature		T _j	150	°C
Storage Temperature Range		T _{stg}	-55 ~ 150	°C

* Package mounted on a ceramic board (600mm² × 0.8mm)



Marking

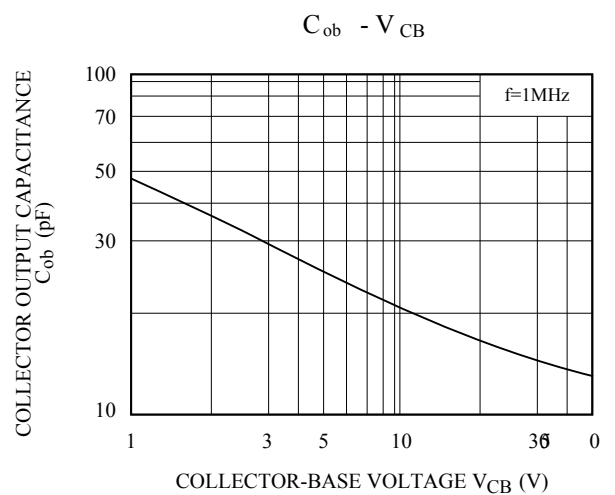
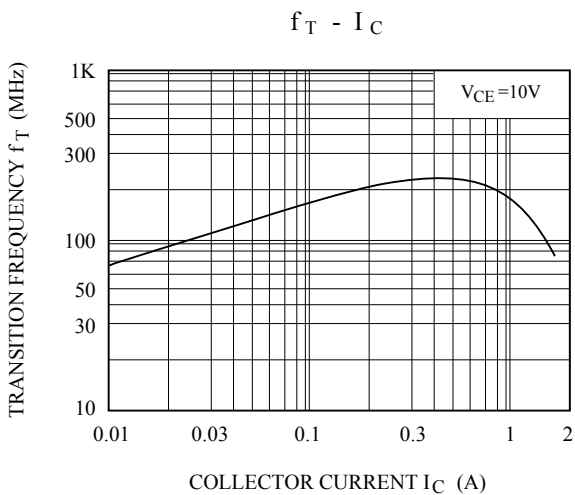
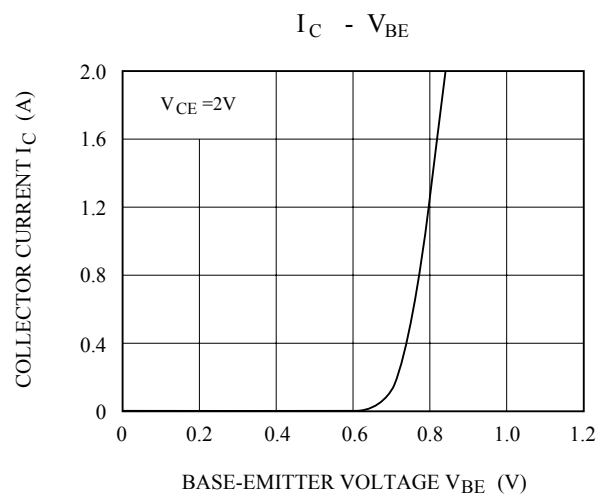
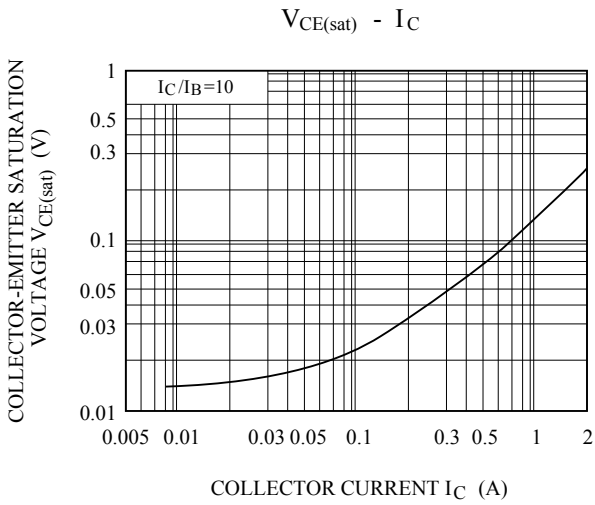
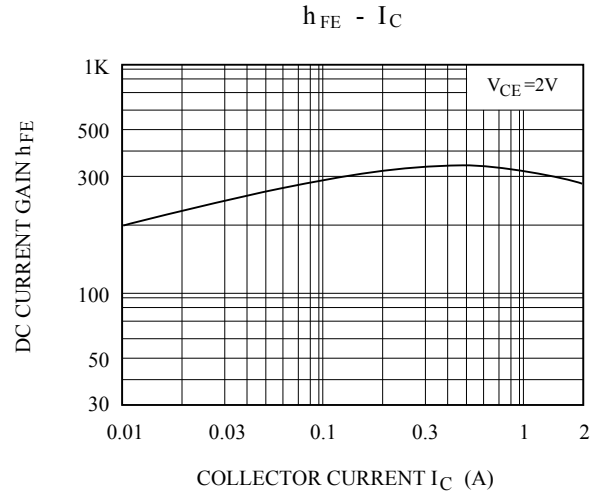
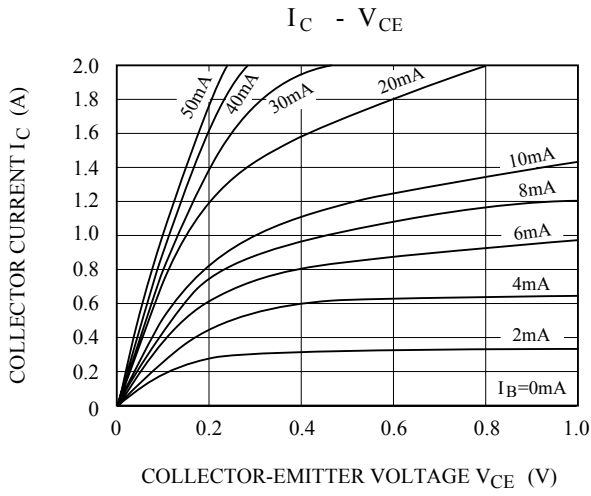


ELECTRICAL CHARACTERISTICS (Ta=25°C)

CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current		I _{CB0}	V _{CB} =20V, I _E =0	-	-	0.1	μA
Emitter Cut-off Current		I _{EBO}	V _{EB} =3V, I _C =0	-	-	0.1	μA
Collector-Base Breakdown Voltage		V _{(BR)CBO}	I _C =10μA, I _E =0	30	-	-	V
Collector-Emitter Breakdown Voltage		V _{(BR)CEO}	I _C =1mA, I _B =0	30	-	-	V
Emitter-Base Breakdown Voltage		V _{(BR)EBO}	I _E =10μA, I _C =0	6	-	-	V
Collector-Emitter Saturation Voltage		V _{CE(sat)}	I _C =1.5A, I _B =75mA	-	180	400	mV
Base-Emitter Saturation Voltage		V _{BE(sat)}	I _C =1.5A, I _B =75mA	-	0.85	1.2	V
DC Current Gain		h _{FE}	V _{CE} =2V, I _C =100mA	200	-	560	
Transition Frequency		f _T	V _{CE} =10V, I _C =50mA	-	150	-	MHz
Collector Output Capacitance		C _{ob}	V _{CB} =10V, f=1MHz	-	19	-	pF
Switching Time	Turn-On Time	t _{on}		-	60	-	nS
	Storage Time	t _{stg}		-	500	-	
	Fall Time	t _f		-	25	-	

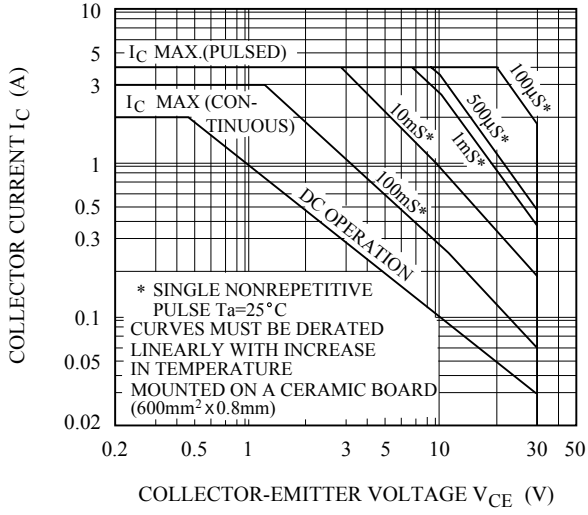


KTC3544T



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SAFE OPERATING AREA



P_c - T_a

